#### TOSHIBA PHOTOCOUPLER PHOTO RELAY

# **TLP3215**

Measuring Instruments
Logic IC Testers / Memory Testers
Board Testers / Scanners

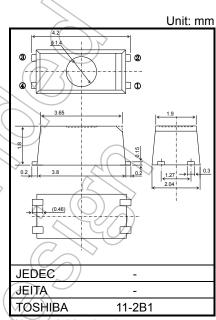
The TOSHIBA TLP3215 is an ultra-small photorelay suitable for surface-mount assembly. The TLP3215 consists of an infrared emitting diode optically coupled to a photo-MOSFET and is housed in a 4-pin package.

The TLP3215 features low CR product and extremely low On-state resistance, allowing high On-state current.

Its features also include low Off-state current and low output pin capacitance, enabling it to be used for high-frequency measuring instrument applications.

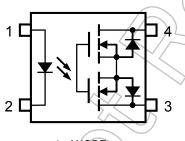
#### **Features**

- 4-pin SSOP (SSOP4): 1.8 mm high, 1.27 mm pitch
- 1-Form-A
- Peak Off-State Voltage: 40 V (min)
- Trigger LED Current: 4 mA (max)
- On-State Current: 300 mA (max)
- On-State Resistance: 1.5  $\Omega$  (max), 1.0  $\Omega$  (typ.)
- Output Capacitance: 14 pF (max), 10 pF (typ.)
- Isolation Voltage: 1500 Vrms (min)
- UL-recognized: UL 1577, File No.E67349



Weight: 0.03 g (typ.)

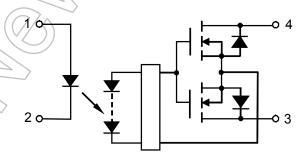
## Pin Configuration (Top View)





4: DRAIN

## Schematic



Start of commercial production 2002-09

### Absolute Maximum Ratings (Ta = 25°C)

|          | CHARACTERISTIC                                | SYMBOL              | RATING     | UNIT    |
|----------|---|---------------------|------------|---------|
|          | Forward Current                               | lF                  | 50         | mA      |
|          | Forward Current Derating (Ta ≥ 25°C)          | ΔI <sub>F</sub> /°C | -0.5       | mA/°C   |
| ۵        | Reverse Voltage                               | V <sub>R</sub>      | 5          | V       |
| 凹        | Diode Power Dissipation                       | $P_{D}$             | 50         | mW      |
|          | Diode Power Dissipation Derating (Ta ≥ 25°C)  | ΔP <sub>D</sub> /°C | -0.5       | mW/°C   |
|          | Junction Temperature                          | Tj                  | 125        | °C      |
|          | Off-State Output Terminal Voltage             | Voff                | 40         |         |
| ~        | On-State Current                              | Ion                 | 300        | mA      |
| СТО      | On-State Current Derating (Ta ≥ 25°C)         | Δlon/°C             | -3.0       | mA/°C   |
| DETECTOR | Output Power Dissipation                      | Po                  | 135        | mW      |
| □        | Output Power Dissipation Derating (Ta ≥ 25°C) | ΔP <sub>o</sub> /°C | -1.35      | mW / °C |
|          | Junction Temperature                          | Tj                  | 125        | °C      |
| Stora    | ge Temperature Range                          | T <sub>stg</sub>    | -40 to 125 | °C      |
| Oper     | ating Temperature Range                       | Topr                | -20 to 85  | © \     |
| Lead     | Soldering Temperature (10 s)                  | T <sub>sol</sub>    | 260        | °C      |
| Isolat   | tion Voltage (AC, 60 s, R.H. ≤ 60 %) (Note 1) | BVs                 | 1500       | Vrms    |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two-terminal device. Pins 1 and 2 shorted together, and pins 3 and 4 shorted together.

#### Caution

This device is sensitive to electrostatic discharge. When using this device, please ensure that all tools and equipment are earthed.

#### **Recommended Operating Conditions**

| CHARACTERISTIC        | SYMBOL | MIN | TYP. | MAX | UNIT |
|-----------------------|--------|-----|------|-----|------|
| Supply Voltage        | VDD    | > - | _    | 32  | V    |
| Forward Current       | /F     | _   | _    | 30  | mA   |
| On-State Current      | ION    | _   | _    | 300 | mA   |
| Operating Temperature | Topr   | -20 | _    | 65  | °C   |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

### **Electrical Characteristics (Ta = 25°C)**

|          | CHARACTERISTIC    | SYMBOL | TEST CONDITION                      | MIN | TYP. | MAX  | UNIT |
|----------|-------------------|--------|-------------------------------------|-----|------|------|------|
|          | Forward Voltage   | VF     | I <sub>F</sub> = 10 mA              | 1.0 | 1.15 | 1.3  | V    |
| LED      | Reverse Current   | lR     | V <sub>R</sub> = 5 V                | _   | _    | 10   | μA   |
| _        | Capacitance       | Ст     | V = 0 V, f = 1 MHz                  | _   | 15   | _    | pF   |
| DETECTOR | Off-State Current | loff   | V <sub>OFF</sub> = 30 V, Ta = 50 °C | ı   | ı    | 1000 | pA   |
| DETE     | Capacitance       | COFF   | V = 0 V, f = 100 MHz, t < 1 s       | -   | 10   | 14   | pF   |

## **Coupled Electrical Characteristics (Ta = 25°C)**

| CHARACTERISTIC      | SYMBOL          | TEST CONDITION   | MIN | TYP. | MAX | UNIT |
|---------------------|-----------------|--|-----|------|-----|------|
| Trigger LED Current | I <sub>FT</sub> | I <sub>ON</sub> = 100 mA                                 | _   | _    | 4   | mA   |
| Return LED Current  | I <sub>FC</sub> | I <sub>OFF</sub> = 10 μA                                 | 0.2 | 0.75 | _   | mA   |
| On-State Resistance | Ron             | I <sub>ON</sub> = 300 mA, I <sub>F</sub> = 5 mA, t < 1 s | 1   | 1.0  | 1.5 | Ω    |

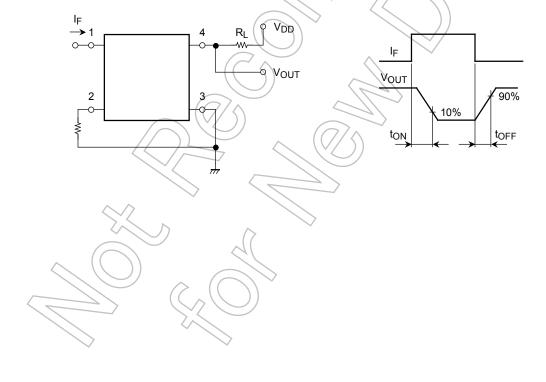
### **Isolation Characteristics (Ta = 25°C)**

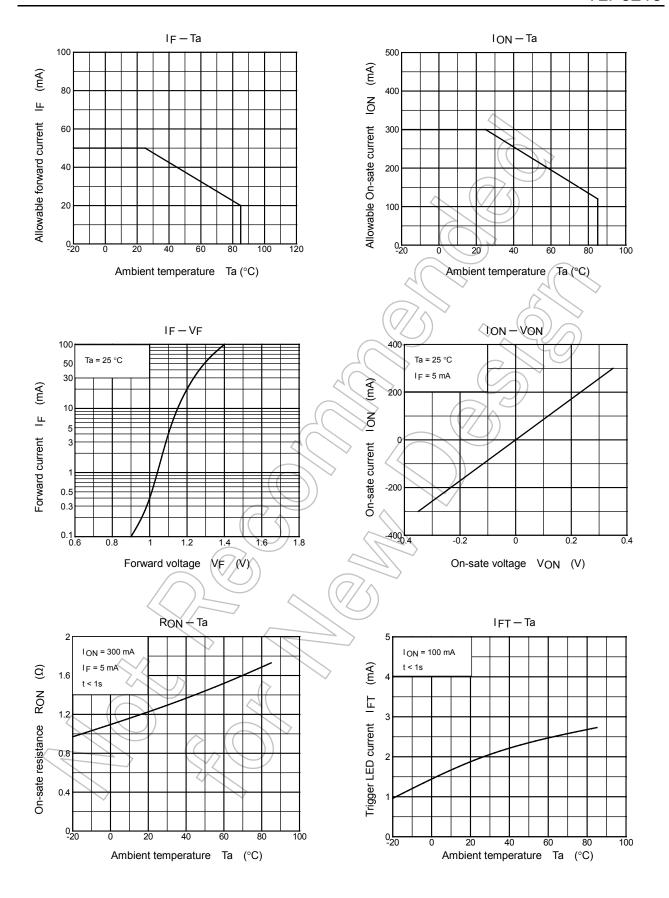
| CHARACTERISTIC              | SYMBOL | TEST CONDITION                      | MIN                  | TYP.             | MAX        | UNIT |
|-----------------------------|--------|-------------------------------------|----------------------|------------------|------------|------|
| Capacitance Input to Output | Cs     | V <sub>S</sub> = 0 V, f = 1 MHz     | / (                  | 0.3              | _          | pF   |
| Isolation Resistance        | Rs     | V <sub>S</sub> = 500 V, R.H. ≤ 60 % | 5 × 10 <sup>10</sup> | 10 <sup>14</sup> | _          | Ω    |
| Isolation Voltage           | BVs    | AC, 60 s                            | 1500                 | 4                | <i> </i> } | Vrms |

### **Switching Characteristics (Ta = 25°C)**

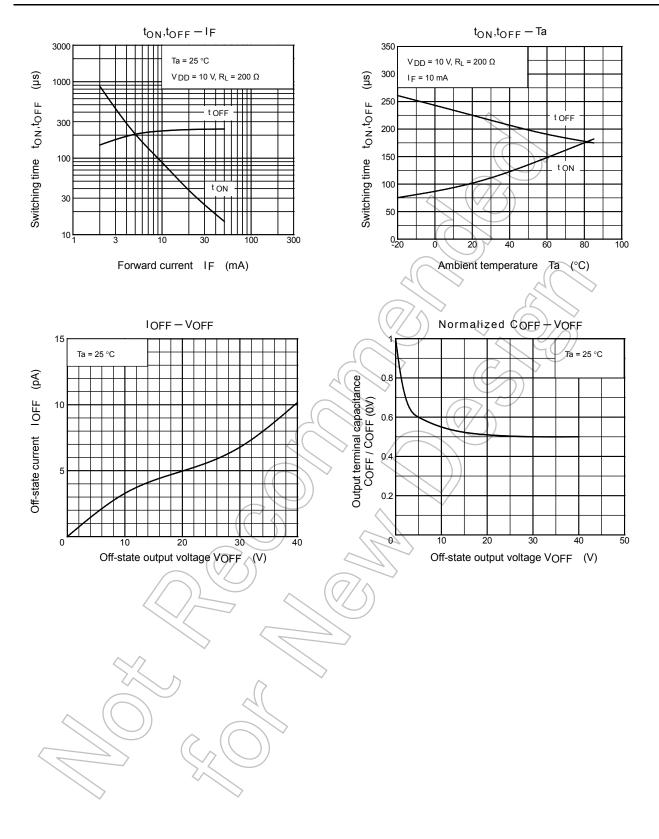
| CHARACTERISTIC | SYMBOL | TEST CONDITION                             | MJN             | TYP. | MAX | UNIT |
|----------------|--------|--|-----------------|------|-----|------|
| Turn-on Time   | ton    | $R_L = 200 \Omega$ (Note 2)                |                 | 200  | 500 |      |
| Turn-off Time  | toff   | $V_{DD} = 10 \text{ V, IF} = 5 \text{ mA}$ | 7 <del>\\</del> | 200  | 500 | μs   |

Note 2: SWITCHING TIME TEST CIRCUIT



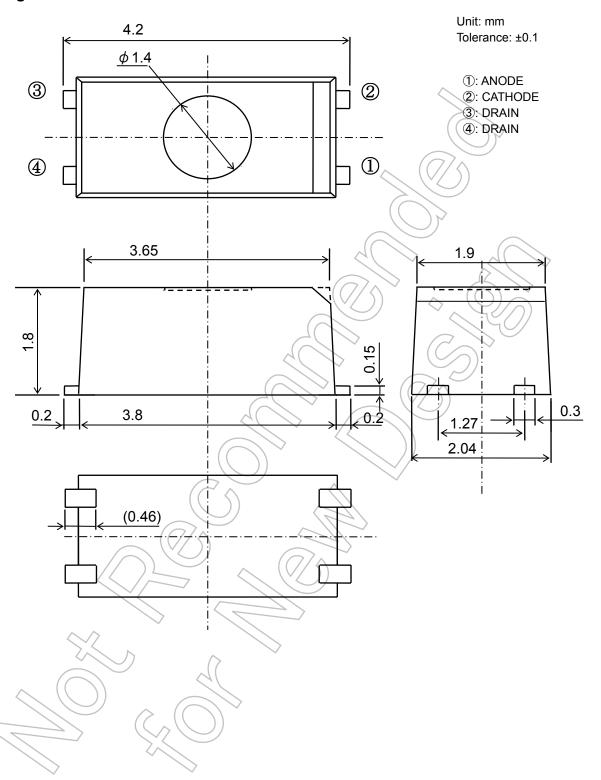


NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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## Package Dimensions



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